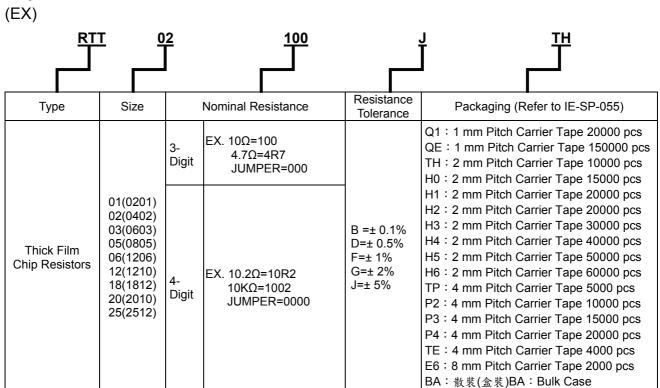
Thick Film Chip Resistors Product Specification

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1 Scope:

- 1.1 This specification is applicable to lead and halogen free RTT series thick film chip resistors.
- 1.2 Lead free products mean lead free termination meets RoHS requirement. Pb contained in glass material of resistor element are exempted by RoHS directive.
- 1.3 The product is for general purpose.
- 1.4 The available AEC-Q200 report also can provide by customer request.

2 Explanation Of Part Numbers:



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3 General Specifications:

3.1 Resistance Range: \geq 1 Ω & 0 Ω

Туре	Rated Power at	Max. Working		Max. Overload	T.C.R (ppm/°C)		Resistan	ce Range		Ra	PER ted rent		PER tance lue
J.	70℃	Voltage	Voltage	(ppm/C)	B(±0.1%) E-24 \ E-96	D(±0.5%) E-24 \ E-96	F(±1%) E-24 \ E-96	G(±2%) \ J(±5%) E-24	J (±5%)	F (±1%)	J (±5%)	F (±1%)	
RTT01	1 20 W	25V	50V	-200 +400		1Ω≦R<10Ω	1Ω≦R<10Ω	1Ω≦R<10Ω	0.5A	0.5A	50mΩ	35mΩ	
(0201)	20			±200	$47\Omega \le R \le 1M\Omega$	$10\Omega\!\leq\!R\!\leq\!10M\Omega$	$10\Omega {\le} R {\le} 10M\Omega$	$10\Omega \! \leq \! R \! \leq \! 10M\Omega$			MAX.	MAX.	
RTT02	1 ,,,	50)/	400)/	±100	$100\Omega {\le} R {\le} 1M\Omega$	10Ω≦R≦1MΩ	10Ω≦R≦22MΩ	10Ω≦R≦22MΩ	4.0	1.5A	50mΩ MAX.	20mΩ	
(0402)	16 W	50V	100V	±200			1Ω≦R<10Ω	1Ω≦R<10Ω	1A			MAX.	
RTT03	_1W	75V	450)/	±100	$100\Omega {\le} R {\le} 1M\Omega$	10Ω≦R≦1MΩ	10Ω≦R≦22MΩ	10Ω≦R≦22MΩ	1A	2A	50mΩ MAX.	20mΩ MAX.	
(0603)	10	/5V	/ 150V	±200		1Ω≦R<10Ω	1Ω≦R<10Ω	1Ω≦R<10Ω					
RTT05	W	450)/	300V	±100	$100\Omega {\le} R {\le} 1M\Omega$	$10\Omega\!\leq\!R\!\leq\!10M\Omega$	10Ω≦R≦27MΩ	10Ω≦R≦27MΩ	2.4	2.5A	50mΩ MAX.	20mΩ MAX.	
(0805)	8 VV	150V	3007	±200		1Ω≦R<10Ω	1Ω≦R<10Ω	1Ω≦R<10Ω	2A				
RTT06	1 ,,,	−W 200V	400V	±100	10Ω≦R≦1MΩ	$10\Omega\!\leq\!R\!\leq\!10M\Omega$	10Ω≦R≦27MΩ	10Ω≦R≦27MΩ	2A	3.5A	50mΩ	20mΩ	
(1206)	4		2000 4000	±200	3Ω≦R<10Ω	1Ω≦R<10Ω	1Ω≦R<10Ω	1Ω≦R<10Ω	ZA	3.5A	MAX.	MAX.	
RTT12	_1W	200V	400V	±100	$100\Omega {\le} R {\le} 1M\Omega$	$10\Omega\!\leq\!R\!\leq\!10M\Omega$	10Ω≦R≦27MΩ	10Ω≦R≦27MΩ	2A	4A	50mΩ MAX.	20mΩ MAX.	
(1210)	W	2007	4000	±200			1Ω≦R<10Ω	1Ω≦R<10Ω	ZA				
RTT18	3 4 W	2001/	400V	±100	$100\Omega {\le} R {\le} 1M\Omega$	$10\Omega\!\leq\!R\!\leq\!10M\Omega$	$10\Omega{\le}R{\le}20M\Omega$	$10\Omega {\le} R {\le} 20M\Omega$	2.4	5A	50mΩ MAX.	20mΩ MAX.	
(1812)	4	200V	4007	±200			1Ω≦R<10Ω	1Ω≦R<10Ω	2A				
RTT20	3 4 W	2001/	400)/	±100	$100\Omega {\le} R {\le} 1M\Omega$	$10\Omega\!\leq\!R\!\leq\!10M\Omega$	$10\Omega{\le}R{\le}20M\Omega$	$10\Omega{\le}R{\le}20M\Omega$	24	5 A	50mΩ	20mΩ MAX.	
(2010)	4 vv	200V	00V 400V	±200			1Ω≦R<10Ω	1Ω≦R<10Ω	2A	5A	MAX.		
RTT25	1W	2001/	400)/	±100	$100\Omega {\le} R {\le} 1M\Omega$	$10\Omega\!\leq\!R\!\leq\!10M\Omega$	$10\Omega{\le}R{\le}20M\Omega$	$10\Omega{\le}R{\le}20M\Omega$	24	7.0	50mΩ	20mΩ	
(2512)	100	200∨	200V 400V	±200			1Ω≦R<10Ω	1Ω≦R<10Ω	2A	7A	MAX.	MAX.	
Oper	rating Ten	perature	Range			−55 °C ~ +	155℃ (0201:-	-55°C ~ +125°	C)				

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3.2 Resistance Range: $< 1\Omega$

	Rated Power	Man Data I	Mana O and a second	TOD	Resistance Range
Type	at 70°C	Max. Rated Current	Max. Overload Current	T.C.R (ppm / °C)	F(±1%) \ G(±2%) \ J((±5%) E-24 \ E-96
				±1500	25 mΩ \leq R $<$ 37 mΩ
				±1200	$37 \text{ m}\Omega \leq R < 60 \text{ m}\Omega$
RTT02	4/40\4/	4.504	0.054	±600	60 mΩ \leq R $<$ 200 mΩ
(0402)	1/16W	1.58A	3.95A	±300	200 mΩ \leq R $<$ 400 mΩ
				±250	400 mΩ \leq R $<$ 600 mΩ
				±200	600 mΩ \leq R $<$ 1000 mΩ
				±1500	10 mΩ \leq R $<$ 37 mΩ
				±1200	$37~\text{m}\Omega \leq R < 60~\text{m}\Omega$
RTT03	1/10W	3.16A	7.91A	±600	60 mΩ \leq R $<$ 100 mΩ
(0603)	1/1000	3.16A	7.91A	±300	100 m Ω \leq R $<$ 200 m Ω
				±600	200 m Ω \leq R $<$ 500 m Ω
				±400	$500~\text{m}\Omega \! \leq \! R \! < \! 1000~\text{m}\Omega$
				±1500	10 mΩ \leq R $<$ 19 mΩ
RTT05 (0805)			8.82A	±1200	19 m $\Omega{\le}R{<}33$ m Ω
	1/8W	3.53A		±800	$33~\text{m}\Omega \leq \text{R} < 50~\text{m}\Omega$
				±600	$50~\text{m}\Omega \leq R < 100~\text{m}\Omega$
				±200	$100~\text{m}\Omega\!\leq\!R\!<\!1000~\text{m}\Omega$
	1/3W	5.77A	14.42A	±1500	10 m Ω \leq R $<$ 19 m Ω
RTT06 (1206)				±1200	19 m $\Omega{\le}R{<}25$ m Ω
				±1000	$25~\text{m}\Omega \leq R < 50~\text{m}\Omega$
				±600	$50~\text{m}\Omega \leq R < 100~\text{m}\Omega$
				±200	$100~\text{m}\Omega\!\leq\!R\!<\!1000~\text{m}\Omega$
				±1500	10 mΩ \leq R $<$ 19 mΩ
RTT12				±1000	19 mΩ \le R $<$ 25 mΩ
(1210)	1/2W	7.07A	17.67A	±700	25 mΩ≦R<50 mΩ
(,				±400	$50 \text{ m}\Omega \leq R < 100 \text{ m}\Omega$
				±200	100 m Ω ≤R<1000 m Ω
				±1500	10 mΩ≦R<19 mΩ
				±1200	19 mΩ \leq R $<$ 25 mΩ
RTT18	3/4W	8.66A	21.65A	±900	25 mΩ≦R<50 mΩ
(1812)	0,111	0.0071	21.00A	±500	50 mΩ≦R<100 mΩ
				±200	100 mΩ≤R<1000 mΩ
				±200	100 mΩ≦R<1000 mΩ
				±1500	10 mΩ≤R<19 mΩ
RTT20				±1200	19 mΩ≦R<25 mΩ
(2010)	3/4W	8.66A	21.65A	±900	$25 \text{ m}\Omega \leq R < 50 \text{ m}\Omega$
•				±500	$50 \text{ m}\Omega \leq R < 100 \text{ m}\Omega$
				±200	100 mΩ≤R<1000 mΩ
				±1500	10 mΩ≦R<19 mΩ
RTT25	4	46.5	05:	±1200	19 mΩ≦R<25 mΩ
(2512)	1 W	10A	25A	±900	$25 \text{ m}\Omega \leq R < 50 \text{ m}\Omega$
·				±500	50 mΩ≤R<100 mΩ
				±200	100 mΩ \leq R $<$ 1000 mΩ
	Operating T	emperature Ra	nge		-55°C ~ +155°C

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3.3 Power Derating Curve:

Туре	RTT01 (0201)	Other		
Operating Temperature Range	-55℃ ~ +125℃	-55°C ~ +155°C		
	For resistors operated in ambient temperatures above 70° C, power rating shall be derated in accordance with figure below.	For resistors operated in ambient temperatures above 70°C, power rating shall be derated in accordance with figure below.		
Figure	100 (8) 80 100 (8) 80 60 0 -55 20 40 60 80 100 120 140 160 Ambient temperature (°C)	100		

3.4 Voltage Rating or Current Rating

3.4.1Resistance Range: $\ge 1\Omega$

Rated Voltage: The resistor shall have a DC continuous working voltage or a rms. AC continuous working voltage at commercial-line frequency and wave form corresponding to the power rating, as determined from the following

$$E = \sqrt{R \times P}$$
 E= Rated voltage (v)

P= Power rating (w)

R= Nominal resistance(Ω)

3.4.2Range: $< 1\Omega$

Rated Current: The resistor shall have a DC continuous working current or a rms. AC continuous working current at commercial-line frequency and wave form corresponding to the power rating, as determined from the following:

$$I = \sqrt{P/R}$$
 I= Rated current (A)

P= Power rating (w)

R= Nominal resistance(Ω)

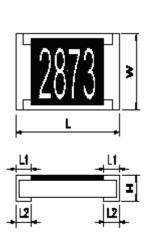
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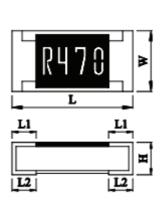
4 Dimensions:

4.1 Resistance Range: \geq 1 Ω & 0 Ω



						Unit:mm
Type	Dimension Size Code	L	W	н	L1	L2
RTT01	0201	0.60±0.03	0.30±0.03	0.23±0.03	0.10±0.05	0.15±0.05
RTT02	0402	1.00±0.10	0.50±0.05	0.30±0.05	0.20±0.10	0.25±0.10
RTT03	0603	1.60±0.10	0.80±0.10	0.45±0.10	0.30±0.15	0.30±0.15
RTT05	0805	2.00±0.10	1.25±0.10	0.50±0.10	0.35±0.20	0.35±0.15
RTT06	1206	3.05±0.10	1.55±0.10	0.50±0.10	0.45±0.20	0.35±0.15
RTT12	1210	3.05±0.10	2.55±0.10	0.55±0.10	0.50±0.20	0.50±0.20
RTT18	1812	4.40±0.20	3.15±0.20	0.47±0.20	0.60±0.20	0.60±0.20
RTT20	2010	5.00±0.20	2.50±0.20	0.55±0.10	0.60±0.20	0.60±0.20
RTT25	2512	6.30±0.20	3.20±0.20	0.55±0.10	0.60±0.20	0.60±0.20

4.2 Resistance Range: $< 1\Omega$



						Unit:mm
	Dimension					
		L	W	Н	L1	L2
_						
Туре	Size Code \					
RTT02	0402	1.00±0.10	0.50±0.05	0.30±0.10	0.25±0.10	0.20±0.15
RTT03	0603	1.60±0.10	0.80±0.10	0.45±0.10	0.25±0.15	0.35±0.15
RTT05	0805	2.00±0.10	1.25±0.10	0.50±0.10	0.35±0.20	0.35±0.20
RTT06	1206	3.05±0.10	1.55±0.10	0.50±0.10	0.45±0.20	0.55±0.25
RTT12	1210	3.05±0.10	2.55±0.10	0.55±0.10	0.50±0.20	0.50±0.20
RTT18	1812	4.40±0.20	3.15±0.20	0.47±0.20	0.60±0.20	0.60±0.20
RTT20	2010	5.00±0.20	2.50±0.20	0.60±0.10	0.65±0.20	0.65±0.20
RTT25	2512	6.30±0.20	3.20±0.20	0.60±0.10	0.65±0.20	0.65±0.20

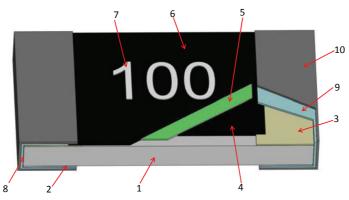
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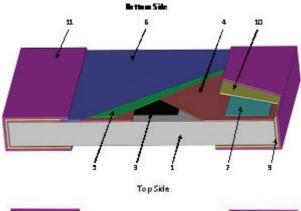
5 Structure Graph:

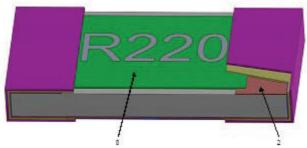
5.1 Resistance Range: $\geq 1\Omega \& 0 \Omega$



1	Ceramic substrate	6	2nd Protective coating
2	Bottom inner electrode	7	Marking
3	Top inner electrode	8	Terminal inner electrode
4	Resistive layer	9	Ni plating
5	1st Protective coating	10	Sn plating

5.2 Resistance Range: $< 1\Omega$





1	Ceramic substrate	7	2 nd Bottom inner electrode
2	Top inner electrode	8	G2 layer + Marking
3	Resistive layer	9	Terminal inner electrode
4	1 st Bottom inner electrode	10	Ni plating
5	1st Protective coating	11	Sn plating
6	2nd Protective coating		

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6 Reliability Test:

6.1 Electrical Performance Test

Item	Conditions	Specifications		
		Resistors	Jumper	
Resistance	TCR (ppm / $^{\circ}$ C) = $^{\circ}$ R1 ($^{\circ}$ Z- $^{\circ}$ T1) ×10 ⁶ R1: Resistance at room temperature R2: Resistance at -55 $^{\circ}$ C or +125 $^{\circ}$ C T1: Room temperature T2: Temperature -55 $^{\circ}$ C or +125 $^{\circ}$ C	Refer to item 3. general specifications	NA	
	Refer to JIS-C5201-1 4.8			
Short Time Overload	Applied 2.5 times rated voltage for 5 seconds and release the load for about 30 minutes, then measure its resistance variance rate. (Rated voltage refer to item 3. general specifications) Jumper: Applied Maximum overload current Type RTT01 RTT02 RTT03 RTT05 RTT06 RTT12 RTT18 RTT20 RTT25 (0201) (0402) (0603) (0805) (1206) (1210) (1812) (2010) (2512)	1.Resistance Range: $\geq 1\Omega$ $0.1\% \cdot 0.5\% \cdot 1\%$: $\pm (1.0\% + 0.05\Omega)$ $2\% \cdot 5\%$: $\pm (2.0\% + 0.10\Omega)$ 2.Resistance Range: $< 1\Omega$ $1\% \cdot 2\% \cdot 5\%$: $\pm (2.0\% + 0.001\Omega)$ No evidence of mechanical damage.	Refer to iter 3. general specification	
	±5% 1.25A 2.5A 2.5A 5A 5	No short or burned on the appearance.		
Resistance	Put the resistor in the fixture, add 100 VDC in + ,- terminal for 60 sec then measured the insulation resistance between electrodes and insulating enclosure or between electrodes and base material. Refer to JIS-C5201-1 4.6 Metal block measuring plate measuring point B insulating plate measuring point B insulating enclosure surface Ro.5mm	$\geq 10^{9}\Omega$		
Dialantria		No short or hurned on the appearance		
Dielectric Withstand Voltage	Put the resistor in the fixture, add VAC (see SPEC below) in +,-terminal for. RTT05 \ 06 \ 12 \ 18 \ 20 \ 25 apply 500 VAC 1 minute. RTT01 \ 02 \ 03 apply 300 VAC 1 minute. Refer to JIS-C5201-1 4.7	No short or burned on the appearance.		
Intermittent Overload	Put the tested resistor in chamber under temperature $25\pm2^{\circ}\mathbb{C}$ and load 2.5 times rated DC voltage for 1 sec on, 25 sec off, 10000^{+400}_{0} test cycles, then it be left at no-load for 1 hour , then measure its resistance variance rate. Jumper : Applied Maximum overload current $\begin{array}{ c c c c c c c c c c c c c c c c c c c$	$ \begin{array}{l} \text{1.Resistance Range:} \geq 1\Omega \\ \pm (5.0\% + 0.10\Omega) \\ \text{2.Resistance Range:} < 1\Omega \\ \pm (5.0\% + 0.001\Omega) \\ \text{No evidence of mechanical damage.} \\ \text{No short or burned on the appearance.} \\ \end{array} $	Refer to iter 3. general specification	
Noise Level	Refer to JIS-C5201-1 4.12	$\begin{array}{c cccc} Resistance & Noise \\ \hline R < 100\Omega & \leq & -10db & (0.32 \text{ uV/V}) \\ \hline 100\Omega \leq R < 1K\Omega & \leq & 0db & (1.0 \text{ uV/V}) \\ \hline 1K\Omega \leq R < 10K\Omega & \leq & 10db & (3.2 \text{ uV/V}) \\ \hline 10K\Omega \leq R < 100K\Omega & \leq & 15db & (5.6 \text{ uV/V}) \\ \hline 100K\Omega \leq R < 1M\Omega & \leq & 20db & (10 \text{ uV/V}) \\ \hline 1M\Omega \leq R & \leq & 30db & (32 \text{ uV/V}) \\ \hline \end{array}$	NA	

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6.2 Mechanical Performance Test

Item	Conditions	Specifications	lumpor
Body Strength	Applied R0.5 test probe at its central part then pushing 10N { 1.02 Kgf } force on the sample for 10 sec. 1.RTT02 \ RTT03 : probe R0.2 2.RTT05 \ 06 \ 12 \ 18 \ 20 \ 25 : probe R0.5	Resistors 1.Resistance Range: ≥ 1Ω ±(1.0%+0.05Ω) 2.Resistance Range:<1Ω ±(1.0%+0.001Ω)	Jumper Refer to item 3. general specifications
	Refer to JIS-C5201-1 4.15	No evidence of mechanical damage. No side conductive peeling off	
_	Test 1: The resistor mounted on the board applied 5N pushing force on the sample rear for 10 sec. (RTT01:3N) Test 2: The resistor mounted on the board slowly add force on the sample rear until the sample termination is breakdown. Refer to JIS-C5201-1 4.16	Test 1 : No evidence of mechanical d Test 2 : RTT01≧3N Other Type≧5N	amage.
	The tested resistor be immersed into isopropyl alcohol of $20\sim25^\circ$ C for 5 minutes, then the resistor is left in the room for 48 hrs, and measured its resistance variance rate.	$ \begin{array}{c cccc} 1. Resistance \ Range: \geqq 1\Omega \\ \hline Type & RTT01 & Other \\ \hline \triangle R\% & \pm (1.0\% + 0.05\Omega) & \pm (0.5\% + 0.05\Omega) \\ 2. Resistance \ Range: < 1\Omega \\ \hline \pm (1.0\% + 0.001\Omega) \\ \end{array} $	Refer to item 3. general specifications
	Refer to JIS-C5201-1 4.29	No evidence of mechanical damage. No G2 overcoating and Sn layer by le	aching.
•	Preconditioning Put the tested resistor in the apparatus of PCT, at a temperature of 105℃, humidity of 100% RH, and pressure of 1.22×105 Pa for a duration of 4 hours. Then after left the tested resistor in room temperature for 2 hours or more. Test method: The resistor be immersed into solder pot in temperature 235±5℃ for 2 sec, then the resistor is left as placed under microscope to observed its solder area. Refer to JIS-C5201-1 4.17	Solder coverage over 95%	
Soldering Heat	⑤Test method 1 (Solder pot test): The tested resistor be immersed into molten solder of 260+5/-0°C for 10 seconds. Then the resistor is left in the room for 1 hour. ⑥Test method 2 (Solder pot test): The tested resistor be immersed into molten solder of 260+5/-0°C for 30 seconds. Then the resistor is left as placed under microscope to observe its solder area. ⑥Test method 3 (Electric iron test): Preheating temperature: 350±10°C Electric iron preheating time: 3+1/-0 sec Preheating the electric iron on electrode termination, as after that step placed the iron over 60 min. and measured its resistance variance rate.	Test item 1: (1).Variance rate on resistance 1.Resistance Range: ≥ 1Ω ΔR%=±(1.0%+0.05Ω) 2.Resistance Range:<1Ω ΔR%=±(1.0%+0.001Ω) (2).No evidence of electrode damage. No side conductive peeling off. Test item 2: (1).Solder coverage over 95%. (2).The underlying material (such as ceramic) shall not be visible at the crest corner area of the electrode. Test item 3: (1).Variance rate on resistance 1.Resistance Range:≥1Ω ΔR%=±(1.0%+0.05Ω) 2.Resistance Range:<1Ω ΔR%=±(1.0%+0.001Ω) (2).No evidence of electrode	Refer to item 3. general specifications
	Refer to JIS-C5201-1 4.18	damage. No side conductive peeling off.	

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Item	Conditions	Specifications	Lumpar
· · · · · · · · · · · · · · · · · · ·			
	h Preconditioning Put tested resistor in the apparatus of PCT, at a temperature of 105°C, humidity of 100% RH, and pressure of 1.22×105 Pa for a duration of 4 hours. Then after left the specimen in a temperature for 2 hours or more. Test method: ○Test item 1 (Adhesion): A static load using a R0.5 (0201:R0.1) scratch tool shall be applied on the core of the component and in the direction of the arrow and held for 10 seconds and under load measured its resistance variance rate. Load:1.RTT01=5N 2.RTT02=10N 3.Other type=20N	Resistors Test item 1: (1).Variance rate on resistance 1.Resistance Range: $\ge 1\Omega$	Jumper Refer to ite 3. general specificatio
Vibration	supporting terminals on the solid table. The entire frequency range: from 10 Hz to 55 Hz and return to 10 Hz, shall be transferred in 1 min. Amplitude: 1.5 mm	1.Resistance Range : $\geq 1~\Omega$ 0.1% \cdot 0.5% \cdot 1%: \pm (0.5%+0.05 Ω) 2% \cdot 5%: \pm (1.0%+0.05 Ω) 2.Resistance Range : $<1~\Omega$ 1% \cdot 2% \cdot 5%: \pm (1.0%+0.001 Ω) No evidence of mechanical damage	Refer to ite 3. general specification

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6.3 Environmental Test

Itom	Conditions		Specifications	
Item	Conditions		Resistors	Jumper
Dry Heat	1000 +48/-0 hours. Then leaving the tested resistor in room temperature for 60 minutes, and measure its resistance variance		1.Resistance Range: ≥ 1Ω 0.1% \ 0.5% \ 1%:±(1.0%+0.05Ω) e 2% \ 5%:±(2.0%+0.10Ω) 2.Resistance Range:<1Ω 1% \ 2% \ 5%:±(1.0%+0.001Ω)	Refer to item 3. general specification
	Refer to JIS-C5201-1 4.25		No evidence of mechanical damage. No short or burned on the appearance	e.
Fhermal Shock	k Put the tested resistor in the chamber under the Thermal Shock which shown in the following table shall be repeated 300 times consecutively. Then leaving the tested resistor in the room temperature for 1 hours, and measure its resistance variance		1.Resistance Range: ≥ 1Ω 0.1% \ 0.5% \ 1%:±(0.5%+0.05Ω) 2% \ 5%:±(1.0%+0.05Ω) 2.Resistance Range:<1Ω 1% \ 2% \ 5%:±(1.0%+0.001Ω)	Refer to iten 3. general specification
	Testing Condit		No evidence of mechanical damage.	
	Lowest Temperature	-55±5°C	No short or burned on the appearance	е.
	Highest Temperature Temperature-retaining time	125±5°ℂ 15 minutes each		
in Moisture °C, relative humidity 90~95% and load the rated voltage for 90 minutes on, 30 minutes off, total 1000 hours. Then leaving the tested resistor in room temperature for 60 minutes, and measure its resistance variance rate.		$\pm (3.0\% + 0.1\Omega)$ $\pm (2.0\% + 0.10\Omega)$ 2.Resistance Range:<1 Ω	Refer to iter 3. general specification	
			1% \ 2% \ 5%:±(2.0%+0.001Ω) No evidence of mechanical damage. No short or burned on the appearance.	
Load Life	Put the tested resistor in chamber und and load the rated voltage for 90 minutotal 1000 hours. Then leaving the test temperature for 60 minutes, and meas variance rate.	tes on, 30 minutes off, ded resistor in room	1.Resistance Range: \ge 1Ω Type RTT01 Other 1%: 0.1% \cdot 0.5% \cdot 1%: ±(1.0%+0.05Ω)±(0.5%+0.05Ω) 5%: 2% \cdot 5%: ±(3.0%+0.1Ω) ±(2.0%+0.10Ω) 2.Resistance Range: <1Ω 1% \cdot 2% \cdot 5%:±(2.0%+0.001Ω)	Refer to item 3. general specifications
	Refer to JIS-C5201-1 4.25		No evidence of mechanical damage. No short or burned on the appearanc	e
Low Temperature Operation	Put the tested resistor in the chamber °C. Decreasing the temperature to -55°c temperature at -55°C for 1 hour. The for 45 minutes on, and 15 minutes off. resistor in room temperature for 8±1 hours of the resistance variance rate. Refer to MIL-R-55342D 4.7.4	and keep the in load the rated voltage. Then leaving the tested	 1.Resistance Range: ≥ 1Ω 0.1% × 0.5% × 1%:±(0.5%+0.05Ω) 2% × 5%:±(1.0%+0.05Ω) 2.Resistance Range:<1Ω 1% × 2% × 5%:±(1.0%+0.001Ω) No evidence of mechanical damage. No short or burned on the appearance 	Refer to item 3. general specification s
Whisker Test	Test item (Thermal Shock test):		Max. 50 μ m	
TTHORES TOOL	Testing Condit	ion	,	
	Minimum storage temperature			
	Maximum storage temperature			
	Temperature-retaining time	10 min.		
	Number of temperature cycles			
	OInspection:	,		
	Inspect for whisker formation on speci acceleration test specified in subciau (stereo microscope) of about 40 or judgment is hard in this method, u microscope (SEM) of about 1,000 or hi	se 4.2, with a magnifie higher magnification. I use a scanning electror	r f	
	By JESD Standard NO.22A121 class 2			

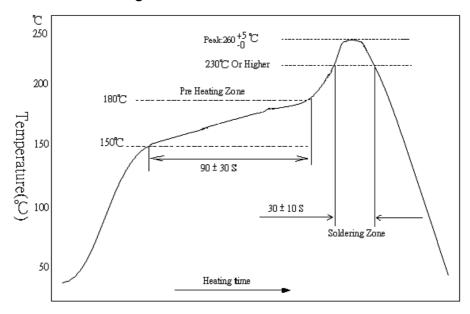
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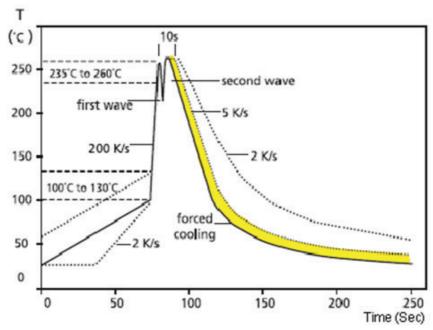
7 Recommend Soldering Method:

7.1 Lead Free Reflow Soldering Profile



Remark: The peak temperature of soldering heat is 260 +5/-0 °C for 10 seconds

7.2 Lead Free Double-Wave Soldering Profile.(This applies to 0603 size inclusive above products)



7.3 Soldering Iron: temperature $350^{\circ}\text{C} \pm 10^{\circ}\text{C}$, dwell time shall be less than 3 sec.

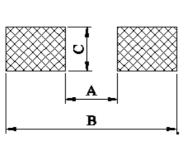
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8 Recommend Land Pattern Design (For Reflow Soldering)

Unit:mm



TYPE DIM	Α	В	С
RTT01	0.3	1.0	0.4
RTT02	0.5	1.5	0.6
RTT03	0.8	2.1	0.9
RTT05	1.2	3.0	1.3
RTT06	2.2	4.2	1.6
RTT12	2.2	4.2	2.8
RTT18	3.1	5.9	3.0
RTT20	3.5	6.1	2.8
RTT25	3.8	8.0	3.5

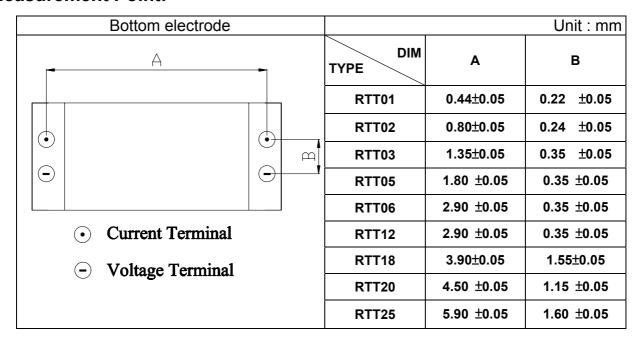
9 Plating Thickness:

9.1 Ni: \ge 2 μ m

9.2 Sn(Tin): \ge 3 μ m

9.3 Sn(Tin):Matte Sn

10 Measurement Point:



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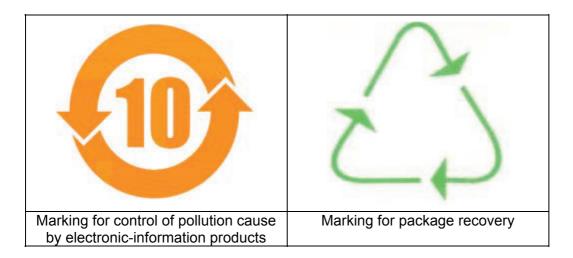
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11 Stock period:

11.1 The temperature condition must be controlled at 25±5°C, the R.H. must be controlled at 60±15%. The stock can maintain quality level in two years.

12 The carton packaged for electronic-information products is made by the symbol as follows: (For china)



13 Attachments:

13.1 Document Revise Record (QA-QR-027)

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